

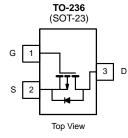
# P-Channel 20 V (D-S) MOSFET

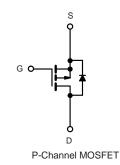
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	- 20			
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 V$	0.068			
$R_{DS(on)} (\Omega)$ at $V_{GS} = -2.5 V$	0.095			
I <sub>D</sub> (A)	- 3.8			
Configuration	Single			

#### FEATURES

- DT-Trench Power MOSFET
- AEC-Q101 Qualified<sup>d</sup>
- 100 %  $R_g$  and UIS Tested
- Compliant to RoHS Directive 2002/95/EC







ABSOLUTE MAXIMUM RATING	<b>S</b> (T <sub>C</sub> = 25 °C, unless	otherwise noted	(k		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V <sub>DS</sub>	- 20	N/	
Gate-Source Voltage		V <sub>GS</sub>	± 8	V	
Continuous Drain Current	T <sub>C</sub> = 25 °C	1	- 3.8		
	T <sub>C</sub> = 125 °C	l <sub>D</sub>	- 2.7		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 3.8	А	
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	- 15		
Single Pulse Avalanche Current	L = 0.1 mH	I <sub>AS</sub>	- 6		
Single Pulse Avalanche Energy		E <sub>AS</sub>	4	mJ	
Mauinum Daura Diasis stiash	T <sub>C</sub> = 25 °C	D	3	W	
Maximum Power Dissipation <sup>b</sup>	T <sub>C</sub> = 125 °C	P <sub>D</sub>	1	vv	
Operating Junction and Storage Temperature Range		TJ, T <sub>sta</sub>	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount <sup>c</sup>	R <sub>thJA</sub>	166	°C/W	
unction-to-Foot (Drain)		R <sub>thJF</sub>	50	C/W	

#### Notes

- a. Package limited.
- b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.
- c. When mounted on 1" square PCB (FR-4 material).
- d. Parametric verification ongoing.

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PARAMETER	SYMBOL	TES	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0, I_D = -250 \ \mu A$		- 20	-	-	v
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$		-	- 1.5	v
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 8 V$		-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = - 20 V	-	-	- 1	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V$	$V_{DS}$ = - 20 V, $T_{J}$ = 125 °C	-	-	- 50	μA
		$V_{GS} = 0 V$	$V_{DS}$ = - 20 V, $T_{J}$ = 175 °C	-	-	- 150	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 4.5 V	$V_{DS} \ge 5 V$	- 8	-	-	Α
		V <sub>GS</sub> = - 4.5 V	I <sub>D</sub> = - 2.8 A	-	0.068	-	Ω
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = -2.5 V$	I <sub>D</sub> = - 2 A	-	0.095	-	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 1.6 V, I <sub>D</sub> = - 2.8 A		-	7	-	S
Dynamic <sup>b</sup>	• •	•					
Input Capacitance	C <sub>iss</sub>			-	340	475	
Output Capacitance	C <sub>oss</sub>	$V_{GS} = 0 V \qquad V_{DS} = -10 V, f = 1 MHz$	-	80	109	pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			-	55	70	
Total Gate Charge <sup>c</sup>	Qg			-	5	8	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = - 4.5 V	5 V V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 2.8 A	-	0.7	-	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>			-	1.3	-	
Gate Resistance	Rg	f = 1 MHz		5.5	10	14.5	Ω
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>				15	22	ns
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD}$ = - 10 V, R <sub>L</sub> = 10 $\Omega$ I <sub>D</sub> $\cong$ - 1 A, V <sub>GEN</sub> = - 4.5 V, R <sub>g</sub> = 1 $\Omega$		-	14	21	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			-	30	45	
Fall Time <sup>c</sup>	t <sub>f</sub>			-	9	15	
Source-Drain Diode Ratings and Characteristics <sup>b</sup>							
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	- 1.2	А
Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> = - 1.6 A, V <sub>GS</sub> = 0		-	- 0.8	- 1.2	V

Notes

a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$ 

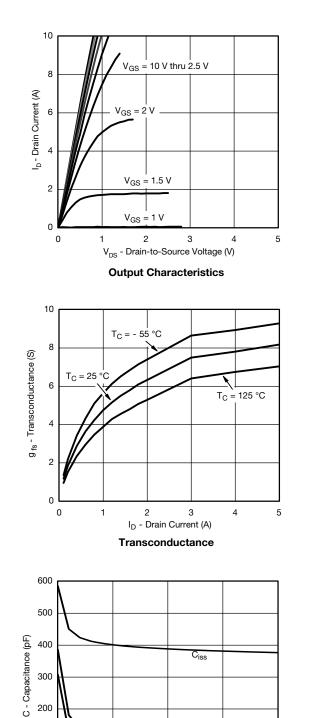
b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Coss

5

10

Capacitance

V<sub>DS</sub> - Drain-to-Source Voltage (V)

15

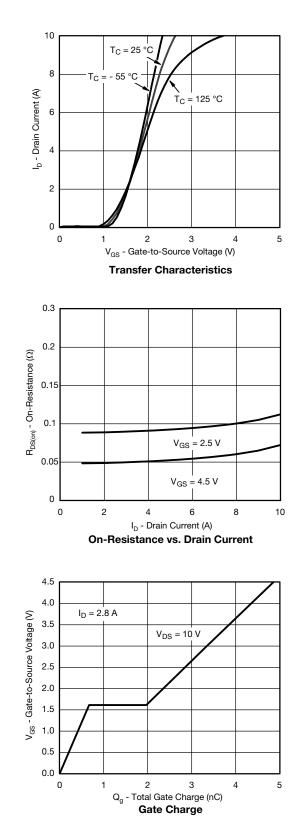
20

 $\mathsf{C}_{\mathsf{rss}}$ 

100

0

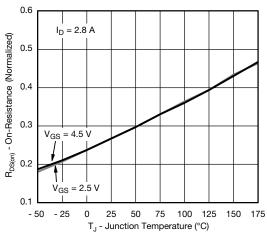
0



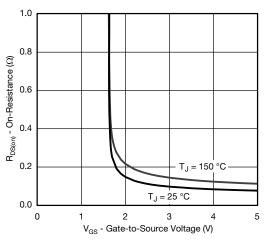


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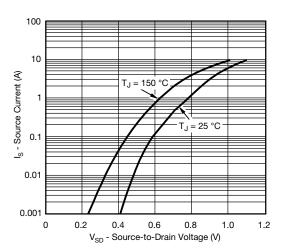
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



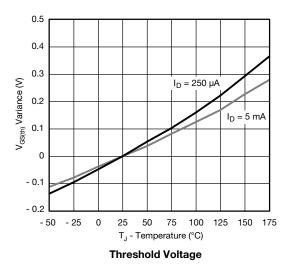
**On-Resistance vs. Junction Temperature** 

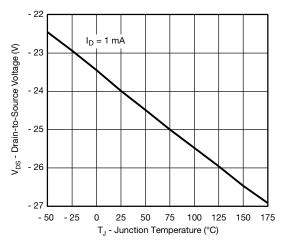


On-Resistance vs. Gate-to-Source Voltage



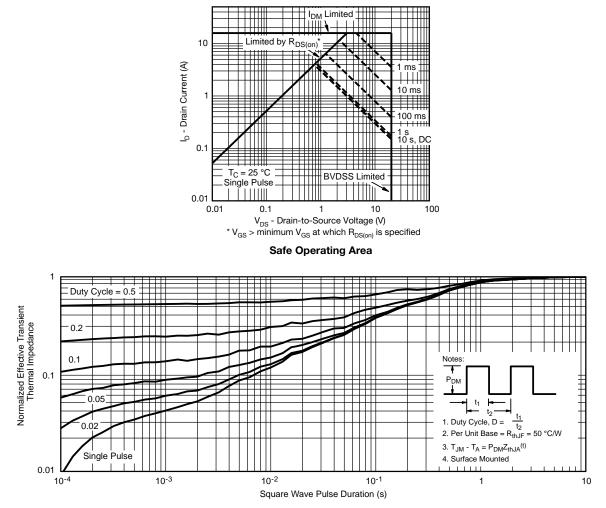
Source-Drain Diode Forward Voltage





Drain Source Breakdown vs. Junction Temperature

#### **THERMAL RATINGS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

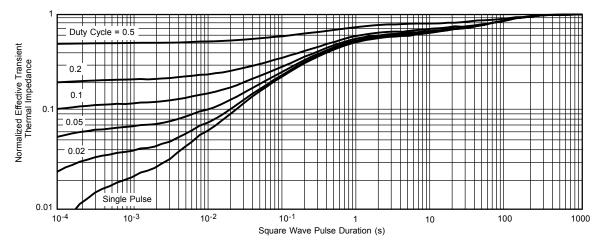


Normalized Thermal Transient Impedance, Junction-to-Foot



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#### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient

#### Note

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Foot (25 C)

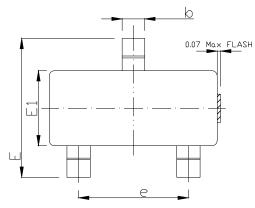
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

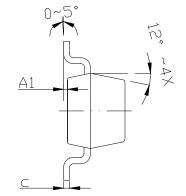
<sup>•</sup> The characteristics shown in the two graphs

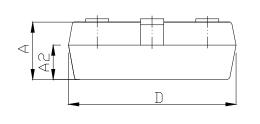


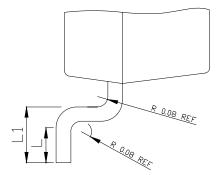
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### SOT-23 PACKAGE OUTLINE









### COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MILLIMETER			
SIMBOL	MIN	NOM	MAX	
A	0.80	1.00	1.30	
A1	0.00	0.05	0.15	
b	0.25	0.40	0.55	
с	0.11 BSC			
D	2 <b>. 6</b> 0	2.90	3.20	
Е	2.10	2.40	2.70	
E1	1.10	1.30	1.48	
е	1.90 BSC			
L	0.17	-	_	
L1	0.28	0.40	0.53	
A2	0.60 REF			



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